Vishay Semiconductors





Cathode	Anode
o	0

SMA

PRODUCT SUMMARY					
Package	SMA				
I _{F(AV)}	1 A				
V _R	40 V				
V _F at I _F	0.49 V				
I _{RM}	26 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	3.0 mJ				

www.vishay.com

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Halogen-free according to IEC 61249-2-21
 definition
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

The VS-10MQ040-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	DC	1	А					
V _{RRM}		40	V					
I _{FSM}	t _p = 5 μs sine	120	А					
V _F	1.5 A _{pk} , T _J = 125 °C	0.56	V					
TJ	Range	- 55 to 150	°C					

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-10MQ040-M3	UNITS				
Maximum DC reverse voltage	V _R	40	V				
Maximum working peak reverse voltage	V _{RWM}	40	v				

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS	
Maximum average forward current		50 % duty cycle at T_L = 123 °C, On PC board 9 mm ² island (0.013 mm thick copper pad area	-	1.5	^	
See fig. 4	I _{F(AV)}	50 % duty cycle at T_L = 132 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		1	A	
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	120	А	
See fig. 6			rated V _{RRM} applied	30	~	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 6 mH		3.0	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.0	А	

Revision: 22-Aug-11

1



RoHS

COMPLIANT HALOGEN

FREE



www.vishay.com

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		1 A	T _{.1} = 25 °C	0.54	V	
Maximum forward voltage drop	V _{EM} ⁽¹⁾	1.5 A	1j = 23° C	0.62		
See fig. 1	VFM (*)	1 A	T ₁ = 125 °C	0.49		
		1.5 A	1j = 125 C	0.56		
Maximum reverse leakage current	I	T _J = 25 °C		0.5	mA	
See fig. 2	I _{RM}	T _J = 125 °C	V _R = Rated V _R	26		
Threshold voltage	V _{F(TO)}	$T_J = T_J$ maximum		0.36	V	
Forward slope resistance	r _t			104	mΩ	
Typical junction capacitance	CT	$V_R = 10 V_{DC}$, $T_J = 25 \text{ °C}$, test signal = 1 MHz		38	pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 2.0		2.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		V/µs		

Note

 $^{(1)}$ Pulse width = 300 $\mu s,$ duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 55 to 150	°C		
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W		
Approximate weight			0.07	g		
Approximate weight			0.002	oz.		
Marking device		Case style SMA (similar D-64)	1	F		

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



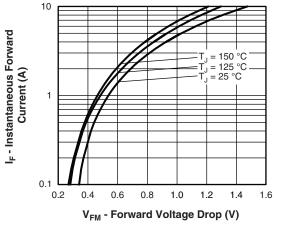
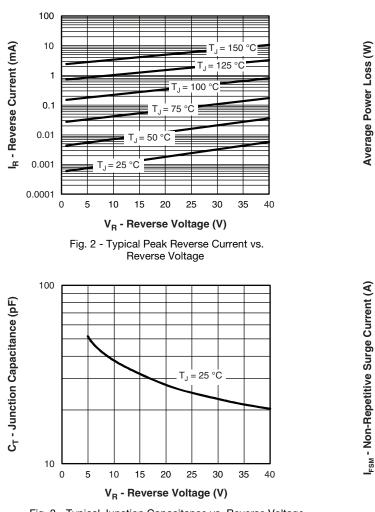
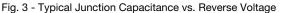


Fig. 1 - Maximum Forward Voltage Drop Characteristics





Vishay Semiconductors

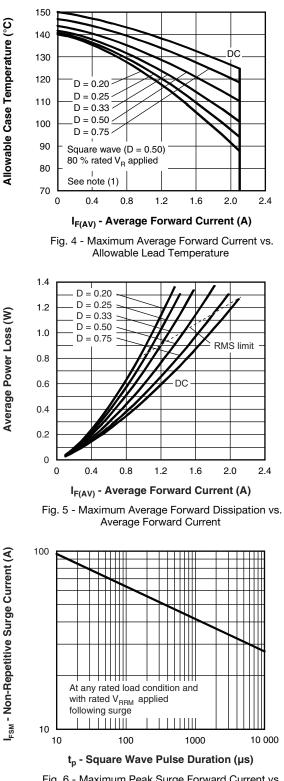


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

Revision: 22-Aug-11

3

Document Number: 93358

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





ORDERING INFORMATION TABLE

Device code	VS-	10	м	Q	040	-M3
		(2)	(3)	(4)	(5)	(6)
	1	- Visl	nay Sem	nicondu	\bigcirc	oduct su
	2 -	Cur	rent rati	ng		
	3 -	- M =	SMA			
	4	- Q =	Schottk	ky "Q" se	eries	
	5	- Vol	tage rati	ng (040	= 40 V))
	6	- Env	rironmer	ntal digit	:	
		-M3	= Halog	gen-free	, RoHS	complia

ORDERING INFORMATION (Example)							
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-10MQ040-M3/5AT	5AT	7500	13" diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95400					
Part marking information	www.vishay.com/doc?95403				
Packaging information	www.vishay.com/doc?95404				



Outline Dimensions

Vishay Semiconductors

SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.